



Solid State Electronics EC210
Arab Academy for Science and Technology
AAST – Cairo
Spring 2016

Lecture 9 Part b

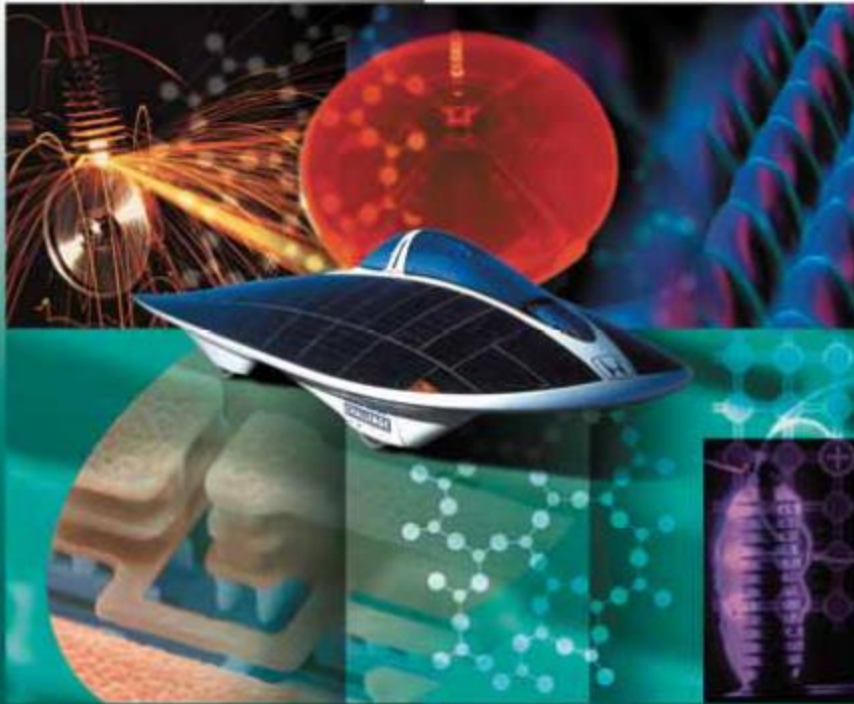
Density of States

Original Lecture Notes Prepared by:

Dr. Amr Bayoumi, Dr. Nadia Rafat

Principles of Electronic Materials and Devices

Third Edition



S. O. Kasap

These PowerPoint color diagrams can only be used by instructors if the 3rd Edition has been adopted for his/her course. Permission is given to individuals who have purchased a copy of the third edition with CD-ROM Electronic Materials and Devices to use these slides in seminar, symposium and conference presentations provided that the book title, author and © McGraw-Hill are displayed under each diagram.



From *Principles of Electronic Materials and Devices, Third Edition*, S.O. Kasap (© McGraw-Hill, 2005)

Original Lecture Notes Prepared by:
Dr. Amr Bayoumi, Dr. Nadia Rafat

Lecture 9: part 2
Density of States

Solid State Electronics EC210, Spring 2016
Arab Academy for Science and Technology
AAST – Cairo,



Introduction

Given a 1D, 2D or 3D material:

How many electrons are allowed to be present within an energy band (such as valence or conduction bands)

- Must find the number of allowed “states” within an Energy range in the E-K diagram, per unit volume (or area or length) of the material
- Each state can hold up to two electrons with different spins
- The band theory does NOT allow infinite numbers of electrons within an energy range
- From the E-K diagram velocity can be found, now only the number of electrons are needed to calculate current

From Principles of Electronic Materials and Devices, Third Edition, S.O. Kasap (© McGraw-Hill, 2005)



Pages

- Kasap:
 - p. 305-308

From Principles of Electronic Materials and Devices, Third Edition, S.O. Kasap (© McGraw-Hill, 2005)



Energy Levels

- **1D ($L_x = a$) :**

$$E_n = \frac{\hbar^2 k_n^2}{2m} = \frac{h^2}{8m a^2} n^2$$

- **2D (assuming $L_x = L_y = a$):**

$$E_n = \frac{\hbar^2 k_n^2}{2m} = \frac{h^2}{8m a^2} (n_x^2 + n_y^2) = \frac{h^2}{8m a^2} n'^2$$

- **3D (assuming $L_x = L_y = L_z = a$) :**

$$E_n = \frac{\hbar^2 k_n^2}{2m} = \frac{h^2}{8m a^2} (n_x^2 + n_y^2 + n_z^2) = \frac{h^2}{8m a^2} n'^2$$

From *Principles of Electronic Materials and Devices, Third Edition*, S.O. Kasap (© McGraw-Hill, 2005)



Density of States (2D)

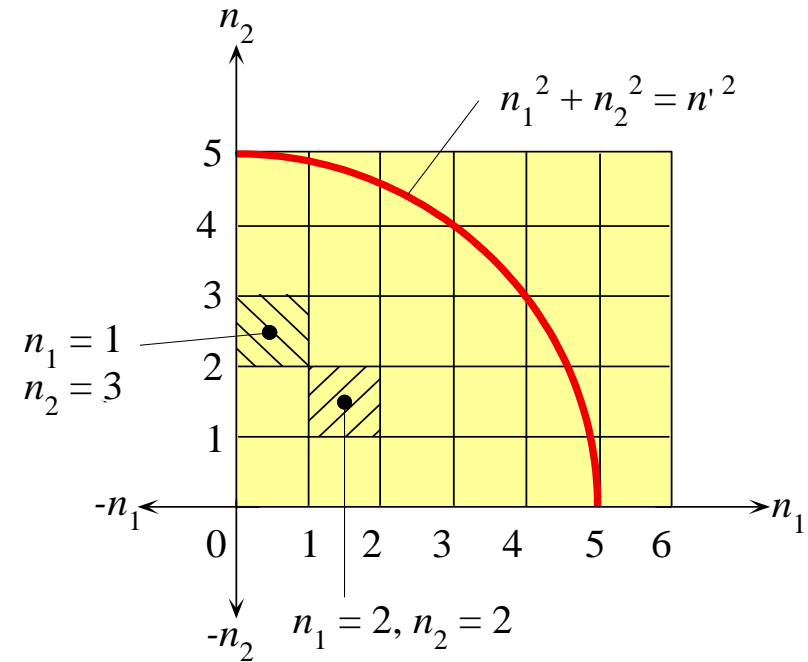
- k and +k are equivalent in k_x k_x and k_y directions
- Number of k states within n' = Area of quarter circle with radius n' :

$$N'_{2D} = \frac{\pi n'^2}{4} = \frac{\pi 8ma^2}{4 h^2} E'$$

- Each state can carry a maximum of two electrons

- Maximum** Number of electrons /unit Area of material =
2 electrons * N'_{2D} /Area:

$$S_{2D}(E) = \frac{2 N'_{2D}}{a^2} = 2 \left[\frac{\pi 8m}{4 h^2} E' \right]$$



Each state, electron wavefunction in the crystal, can be represented by a box at n_1, n_2 .

From *Principles of Electronic Materials and Devices, Third Edition*, S.O. Kasap (© McGraw-Hill, 2005)

Density of States (3D)

- Number of k-states per unit area per unit volume within E' :

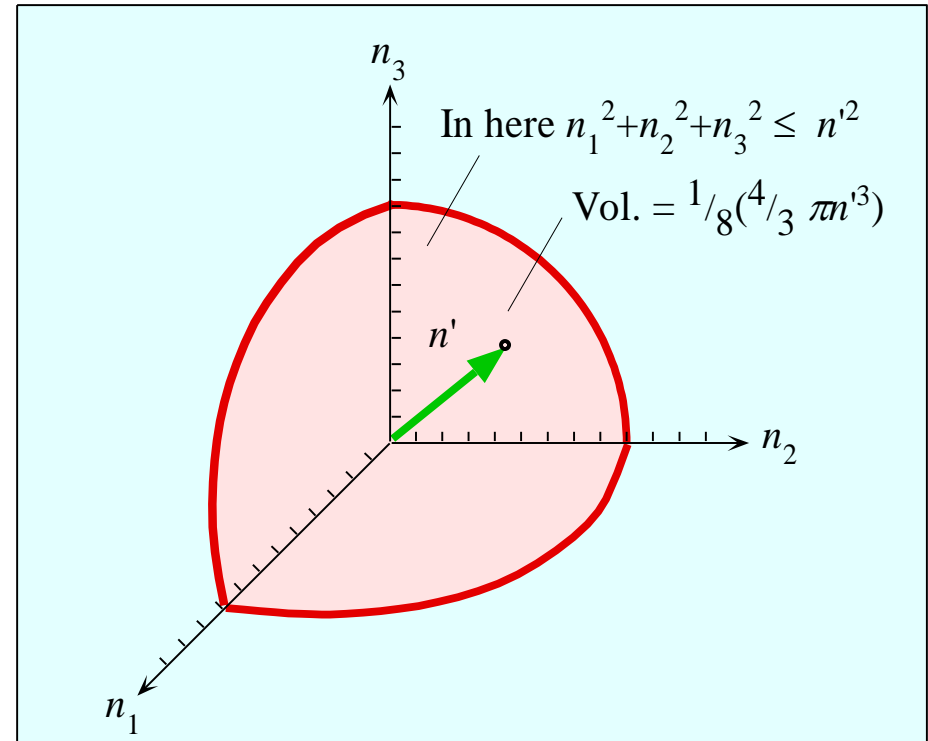
$$N'_{3D}(E') = \frac{\frac{4}{3}\pi n'^3}{8}$$

$$= \frac{\pi}{6} \left[\frac{8ma^2}{h^2} E' \right]^{3/2}$$

- Max.** Number of electrons within E' / unit Volume of material:

$$S_{3D}(E) = 2 \frac{N'_{3D}(E')}{a^3}$$

$$= \frac{\pi}{3} \left[\frac{8m}{h^2} E' \right]^{3/2}$$



In three dimensions, the volume defined by a sphere of radius n' and the positive axes n_1 , n_2 and n_3 , is all the possible combinations of positive n_1 , n_2 and n_3 , values which satisfy $n_1^2 + n_2^2 + n_3^2 \leq n'^2$.

From *Principles of Electronic Materials and Devices, Third Edition*, S.O. Kasap (© McGraw-Hill, 2005)



Density of States (3D)

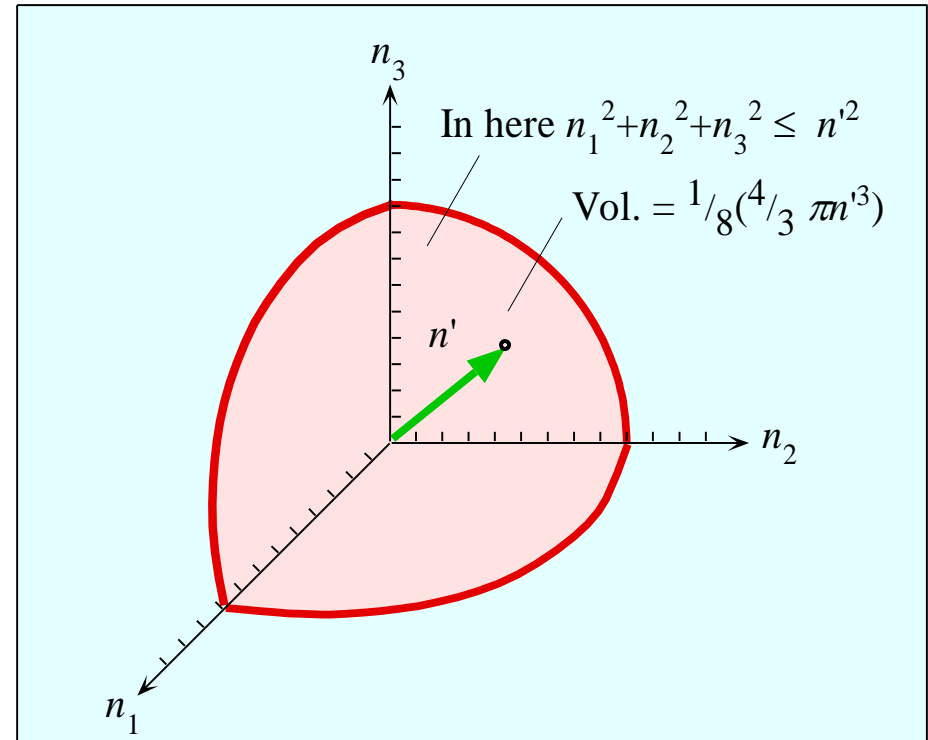
- Density of States = $g(E)$ = **Maximum** Number of electrons per unit **Energy** per unit **Volume**:

$$g_{3D}(E) = \frac{d}{dE} \left\{ \frac{N_{\text{electrons}}(E)}{\text{Vol}} \right\}$$

$$= \frac{d}{dE} \{S_{3D}(E)\}$$

$$= \frac{d}{dE} \left\{ \frac{\pi}{3} \left[\frac{8m}{h^2} E \right]^{\frac{3}{2}} \right\}$$

$$= (\pi/2) \left[\frac{8m}{h^2} \right]^{\frac{3}{2}} \{E^{1/2}\}$$



In three dimensions, the volume defined by a sphere of radius n' and the positive axes n_1, n_2 and n_3 , is all the possible combinations of positive n_1, n_2 and n_3 , values which satisfy $n_1^2+n_2^2+n_3^2 \leq n'^2$.

From *Principles of Electronic Materials and Devices, Third Edition*, S.O. Kasap (© McGraw-Hill, 2005)

Total Number of Electrons allowed between E1 and E2 on the E-K Diagram



$$N_{e,Total} = \int_{E1}^{E2} g(E) dE$$

From *Principles of Electronic Materials and Devices, Third Edition*, S.O. Kasap (© McGraw-Hill, 2005)